**TERMINAL** 

**DISCLAIMER** 

6583015 6583015

**CLAIMS ALLOWED** 

U.S. UTILITY Patent Application

O.I.P.E. PATENT DATE

SCANNED HC O.A. UN 2 4 2003

APPLICATION NO. CONT/PRIOR CLASS SUBCLASS ART UNIT 2811 (1/2/5/4/2)

Eugene Fitzgerald Richard Hammond Matthew Currie

Gate technology for strained surface channel and strained buried channel MOSFET devices

## BEST AVAILABLE COPY

ISSUING CLASSIFICATION

ORIGINAL CROSS REFERENCE(S)

CLASS SUBCLASS CLASS SUBCLASS (ONE SUBCLASS PER BLOCK)

1/3/8 297 438 300 305

INTERNATIONAL CLASSIFICATION

INTERNATIONAL CLASSIFIC

**DRAWINGS** 

DISCLAIMER					
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
	1012	18	Fish	25	1,13,20
☐ The term of this patent	(date) Wilter Lindsay or 1/25/03			NOTICE OF ALLOWANCE MAILED	
subsequent to(date) has been disclaimed.					4
The term of this patent shall not extend beyond the expiration date	John F. Niebling Supervisory Patent Examiner Technology Center 2800) (Primary Examiner) (pate)			1/28/03	
of U.S Patent. No.				ISSUE FEE (N	
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this patent have been disclaimed.	(Legal Instrumen	its Examiner)	$\frac{2 5 03}{\text{(Dafe)}}$		
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